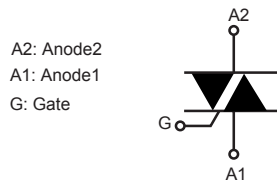
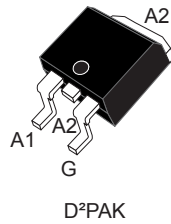


## 16 A logic level (sensitive) Triac



## Features

- High static dV/dt
- High dynamic turn-off commutation (dI/dt)<sub>c</sub>
- 150 °C maximum junction temperature
- Three quadrants
- Surge capability  $V_{DSM}$ ,  $V_{RSM} = 900$  V
- Benefits:
  - High immunity to false turn-on thanks to high static dV/dt
  - Better turn-off in high temperature environments thanks to (dI/dt)<sub>c</sub>
  - Increase of thermal margin due to extended working  $T_j$  up to 150 °C
  - Good thermal resistance due to non-insulated tab.

## Applications

- General purpose AC line load switching
- Motor control circuits
- Home appliances
- Heating
- Lighting
- Inrush current limiting circuits
- Overvoltage crowbar protection

## Product status link

T1610T-8G

## Product summary

$I_{T(RMS)}$	16 A
$V_{DRM}/V_{RRM}$	800 V
$V_{DSM}/V_{RSM}$	900 V
$I_{GT}$	10 mA

## Description

Available in SMD, the T1610T-8G Triac can be used for the on/off or phase angle control function in general purpose AC switching where high commutation capability is required. This device can be used without a snubber RC circuit when the limits defined are respected.

D<sup>2</sup>PAK Package is UL-94,V0 flammability resin compliance.

Package environmentally friendly Ecopack<sup>®</sup>2 graded (RoHS and Halogen Free compliance).

Snubberless<sup>™</sup> is a trademark of STMicroelectronics.

# 1 Characteristics

**Table 1. Absolute maximum ratings (limiting values),  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Symbol	Parameter	Value	Unit	
$V_{\text{DRM}}/V_{\text{RRM}}$	Repetitive peak off-state voltage (50-60 Hz)	$T_j = 125\text{ }^\circ\text{C}$	800	V
		$T_j = 150\text{ }^\circ\text{C}$	600	V
$V_{\text{DSM}}/V_{\text{RSM}}$	Non Repetitive peak off-state voltage	$t_p = 10\text{ ms}, T_j = 25\text{ }^\circ\text{C}$	900	V
$I_{\text{T(RMS)}}$	RMS on-state current (full sine wave)	$T_c = 126\text{ }^\circ\text{C}$	16	A
$I_{\text{TSM}}$	Non repetitive surge peak on-state current (full cycle, $T_j$ initial = $25\text{ }^\circ\text{C}$ )	$t = 16.7\text{ ms}$	126	A
		$t = 20\text{ ms}$	120	
$I^2t$	$I^2t$ value for fusing	$t_p = 10\text{ ms}$	95	$\text{A}^2\text{s}$
$di/dt$	Critical rate of rise of on-state current, $I_G = 2 \times I_{\text{GT}}, tr \leq 100\text{ ns}$	$f = 100\text{ Hz}$	100	$\text{A}/\mu\text{s}$
$I_{\text{GM}}$	Peak gate current	$t_p = 20\text{ }\mu\text{s}, T_j = 150\text{ }^\circ\text{C}$	4	A
$V_{\text{GM}}$	Peak Gate Voltage		5	V
$P_{\text{G(AV)}}$	Average gate power dissipation	$T_j = 150\text{ }^\circ\text{C}$	1	W
$T_{\text{stg}}$	Storage junction temperature range		-40 to +150	$^\circ\text{C}$
$T_j$	Operating junction temperature range		-40 to +150	$^\circ\text{C}$

**Table 2. Electrical characteristics ( $T_j = 25\text{ }^\circ\text{C}$ , unless otherwise specified)**

Symbol	Test conditions	Quadrants; $T_j$	Value	Unit
$I_{\text{GT}}^{(1)}$	$V_D = 12\text{ V}, R_L = 30\text{ }\Omega$	I - II - III	Max. 10	mA
$V_{\text{GT}}$	$V_D = 12\text{ V}, R_L = 30\text{ }\Omega$	I - II - III	Max. 1.3	V
$V_{\text{GD}}$	$V_D = 800\text{ V}, R_L = 3.3\text{ k}\Omega$ <span style="margin-left: 20px;"><math>T_j = 125\text{ }^\circ\text{C}</math></span>	I - II - III	Min. 0.2	V
$I_{\text{L}}$	$I_G = 1.2 \times I_{\text{GT}}$	I - III	Max. 20	mA
	$I_G = 1.2 \times I_{\text{GT}}$	II	Max. 30	mA
$I_{\text{H}}^{(2)}$	$I_T = 500\text{ mA}$ , gate open		Max. 25	mA
$dV/dt^{(2)}$	$V_D = 536\text{ V}$ , gate open	$T_j = 125\text{ }^\circ\text{C}$	Min. 100	$\text{V}/\mu\text{s}$
	$V_D = 402\text{ V}$ , gate open	$T_j = 150\text{ }^\circ\text{C}$	Min. 50	$\text{V}/\mu\text{s}$
$(di/dt)_c^{(2)}$	$(dV/dt)_c = 0.1\text{ V}/\mu\text{s}$	$T_j = 125\text{ }^\circ\text{C}$	Min. 9	A/ms
		$T_j = 150\text{ }^\circ\text{C}$		
	$(dV/dt)_c = 10\text{ V}/\mu\text{s}$	$T_j = 125\text{ }^\circ\text{C}$	Min. 3	A/ms
		$T_j = 150\text{ }^\circ\text{C}$		

1. Minimum  $I_{\text{GT}}$  is guaranteed at 5% of  $I_{\text{GT max}}$

2. For both polarities of A2 referenced to A1.

**Table 3. Static characteristics**

Symbol	Test conditions	$T_j$		Value	Unit
$V_{TM}^{(1)}$	$I_T = 22.6 \text{ A}$ , $t_p = 380 \text{ } \mu\text{s}$	25 °C	Max.	1.55	V
$V_{TO}^{(1)}$	Threshold on-state voltage	150 °C	Max.	0.85	V
$R_D^{(1)}$	Dynamic resistance	150 °C	Max.	34	mΩ
$I_{DRM}/I_{RRM}$	$V_{DRM} = V_{RRM} = 800 \text{ V}$	25 °C	Max.	5	μA
		125 °C		1.0	mA
	$V_{DRM} = V_{RRM} = 600 \text{ V}$	150 °C	Max.	3.6	mA

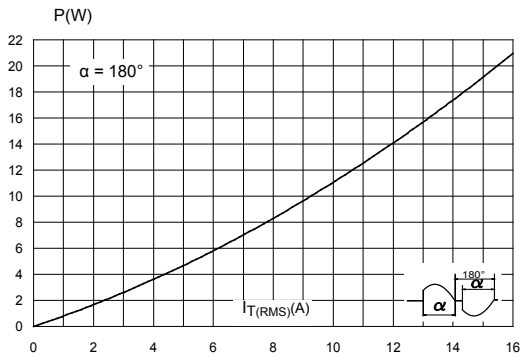
1. For both polarities of A2 referenced to A1.

**Table 4. Thermal resistance**

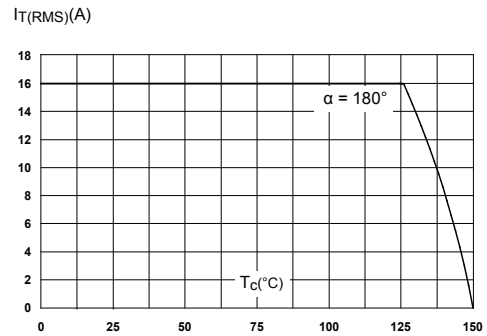
Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	D <sup>2</sup> PAK	Max.	1.15 °C/W

## 1.2 Characteristics (curves)

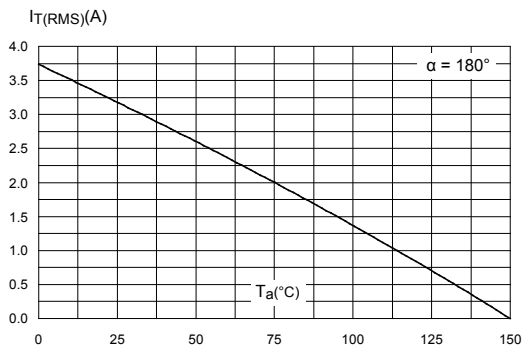
**Figure 1. Maximum power dissipation versus on-state RMS current**



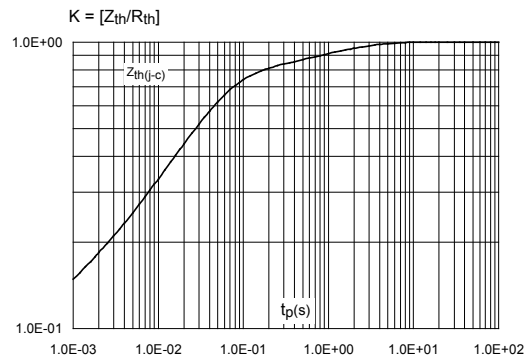
**Figure 2. On-state RMS current versus case temperature**



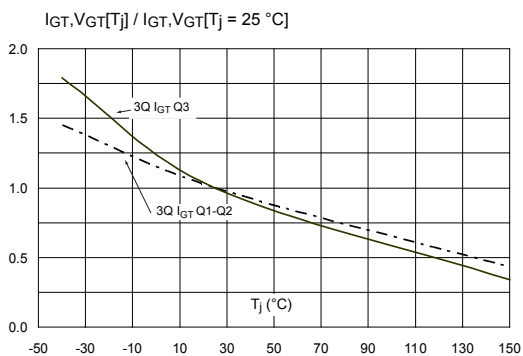
**Figure 3. On-state RMS current versus ambient temperature (free air convection)**



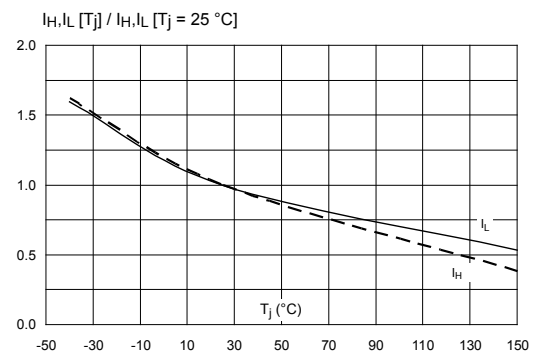
**Figure 4. Relative variation of thermal impedance versus pulse duration**



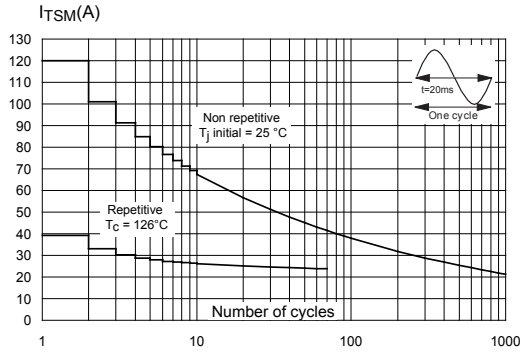
**Figure 5. Relative variation of gate trigger voltage and current versus junction temperature (typical values)**



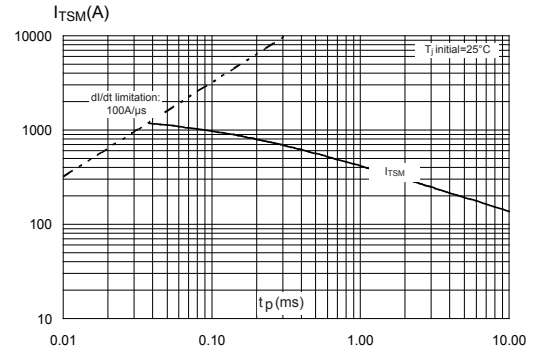
**Figure 6. Relative variation of holding current and latching current versus junction temperature (typical values)**



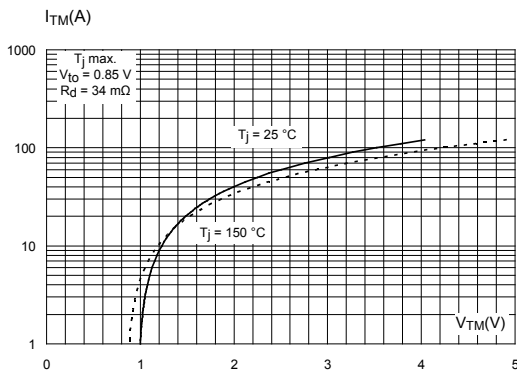
**Figure 7. Surge peak on-state current versus number of cycles**



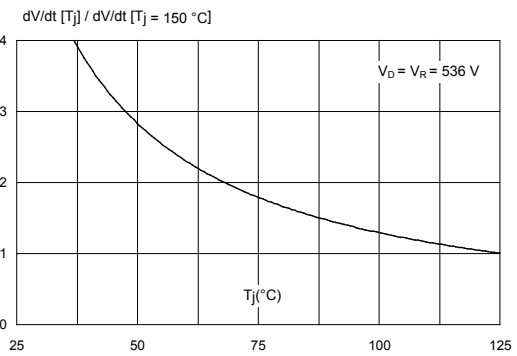
**Figure 8. Non repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10$  ms**



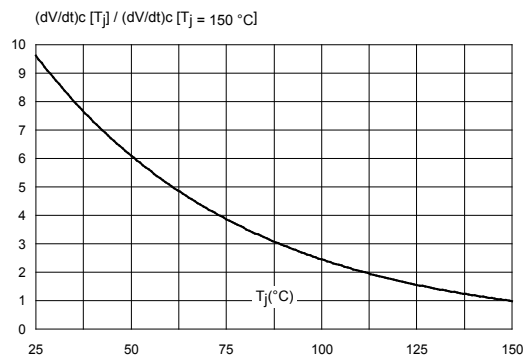
**Figure 9. On-state characteristics (maximum values)**



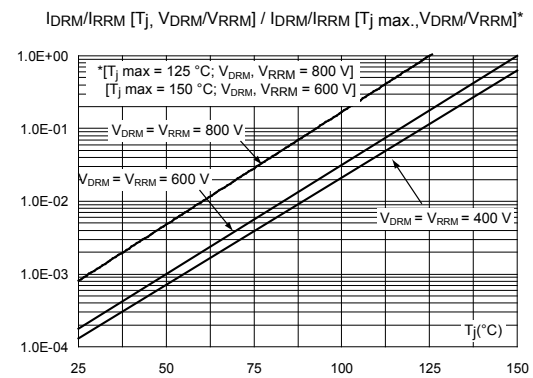
**Figure 10. Relative variation of critical rate of decrease of main voltage versus junction temperature**



**Figure 11. Relative variation of critical rate of decrease of main current versus junction temperature (typical values)**

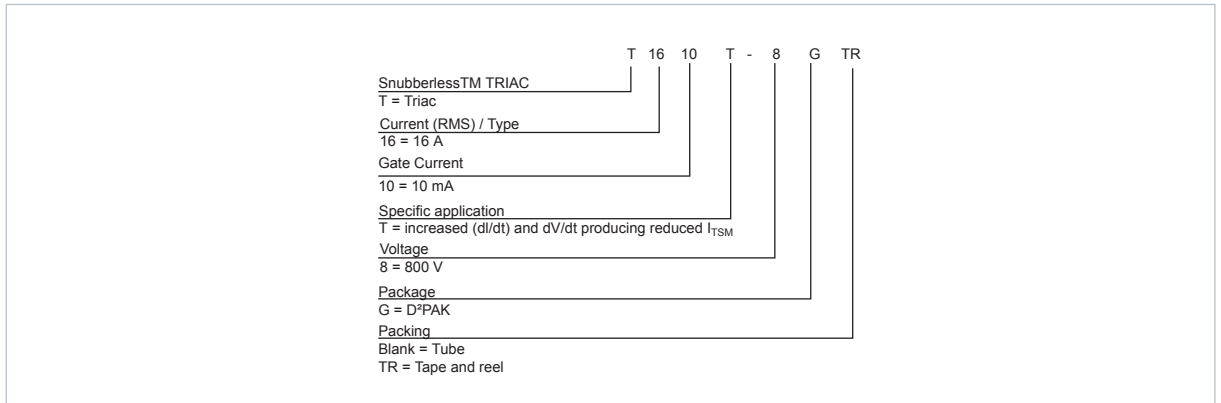


**Figure 12. Relative variation of leakage current versus junction temperature for different values of blocking voltage**



## 2 Ordering information

**Figure 13. Ordering information scheme**



**Table 5. Ordering information**

Order code	Marking	Package	Weight	Base qty.	Delivery mode
T1610T-8G-TR	T1610T-8G	D <sup>2</sup> PAK	1.38 g	1000	Tape and reel
T1610T-8G				50	Tube

### 3 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

#### 3.1 D<sup>2</sup>PAK package information

- ECOPACK2® compliant
- Lead-free package leads finishing
- Molding compound resin is halogen-free and meets UL standard level V0

Figure 14. D<sup>2</sup>PAK package outline

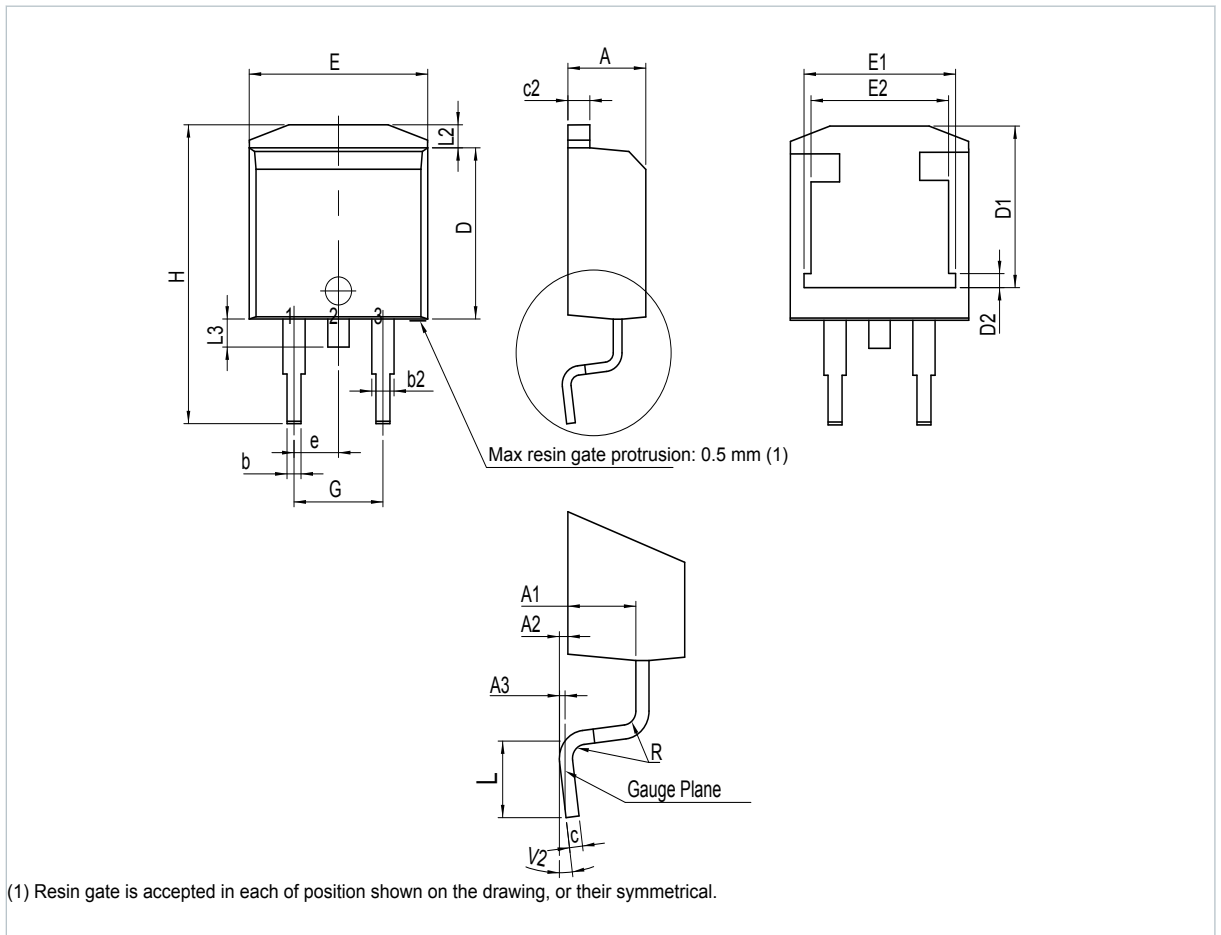


Table 6. D<sup>2</sup>PAK package mechanical data

Ref.	Dimensions					
	Millimeters			Inches <sup>1</sup>		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.60	0.1693		0.1811
A1	2.49		2.69	0.0980		0.1059
A2	0.03		0.23	0.0012		0.0091
A3		0.25			0.0098	
b	0.70		0.93	0.0276		0.0366
b2	1.25		1.7	0.0492		0.0669
c	0.45		0.60	0.0177		0.0236
c2	1.21		1.36	0.0476		0.0535
D	8.95		9.35	0.3524		0.3681
D1	7.50		8.00	0.2953		0.3150
D2	1.30		1.70	0.0512		0.0669
e		2.54			0.1	
E	10.00		10.28	0.3937		0.4047
E1	8.30		8.70	0.3268		0.3425
E2	6.85		7.25	0.2697		0.2854
G	4.88		5.28	0.1921		0.2079
H	15		15.85	0.5906		0.6240
L	1.78		2.28	0.0701		0.0898
L2	1.27		1.40	0.0500		0.0551
L3	1.40		1.75	0.0551		0.0689
R		0.40			0.0157	
V22	0°		8°	0°		8°

1. Dimensions in inches are given for reference only
2. Degrees



Figure 15. D<sup>2</sup>PAK recommended footprint (dimensions are in mm)

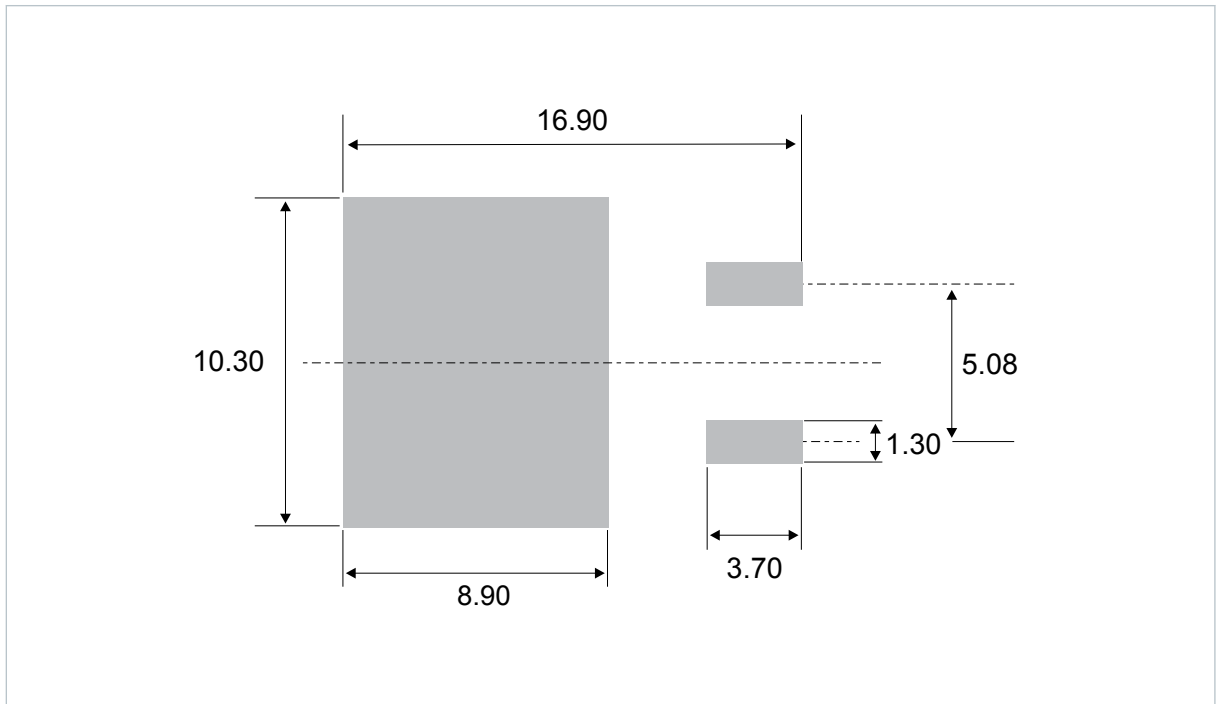
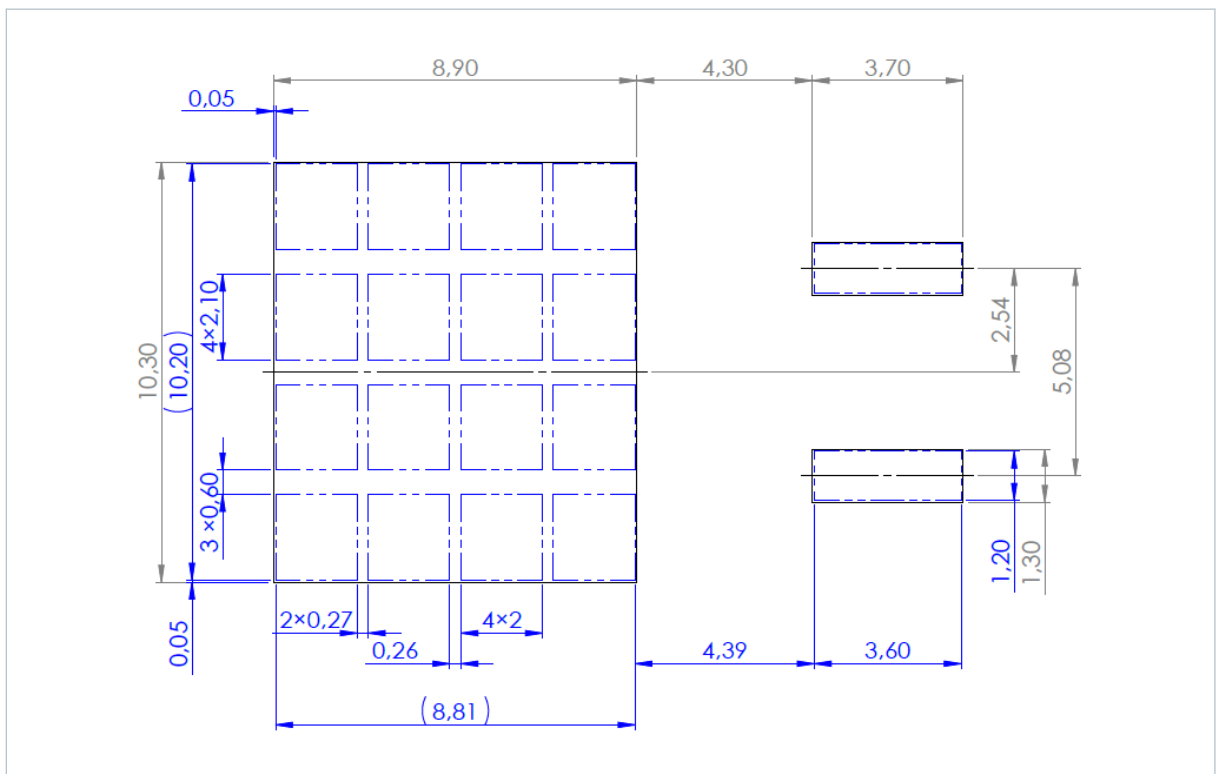


Figure 16. D<sup>2</sup>PAK stencil definitions (dimensions are in mm)



## Revision history

**Table 7. Document revision history**

Date	Version	Changes
03-Apr-2018	1	Initial release.
17-Jul-2018	2	Updated <a href="#">Table 2</a> . Electrical characteristics ( $T_j = 25\text{ }^\circ\text{C}$ , unless otherwise specified).

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- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
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